**TOSHIBA** TA8062S

TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

# TA8062S

#### **DUAL HIGHSIDE DRIVER**

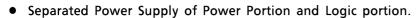
The TA8062S is a 0.3A highside driver containing two circuits in one package.

The input level is TTL compatible so that the output can be controlled directly from CPU system and the like. Protective functions are built in to protect IC and load from destruction caused of over stress.

#### **FEATURES**

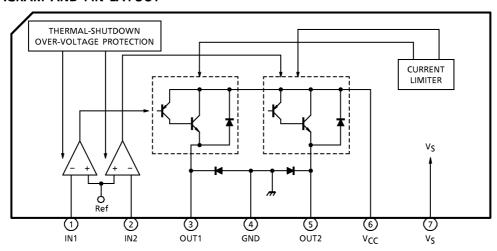
- 2 circuit in one package.
- Output current capacity: 0.3A
- : Over-voltage Protection Protective function

**Current Limiter** Thermal-Shutdown



- Built-in Counter Electromotive Force Absorption Diodes.
- SIP7pin Plastic Package.

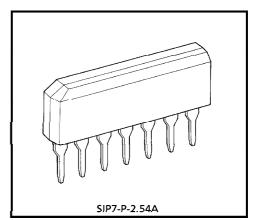
#### **BLOCK DIAGRAM AND PIN LAYOUT**



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Weight: 0.7g (Typ.)

### **PIN DESCRIPTION**

PIN No.	SYMBOL	DESCRIPTION
1	IN1	These terminals control output condition.
2	IN2	The input level is TTL Compatible.
3	OUT1	PNP-type complementary output pin with a current capacity of 0.3A. When the output pin is supplied with a current exceeding the detection current
5	OUT2	(typically 0.55A) because of load short-circuit, the output is limited to protect the IC.
4	GND	Ground terminal.
6	VCC	Power supply terminal for the output part of IC. Built-in over-voltage function protects IC and load when the supplied voltages higher than 30V.
7	VS	Power supply terminal for the control part of IC and this pin is separated from V <sub>CC</sub> .

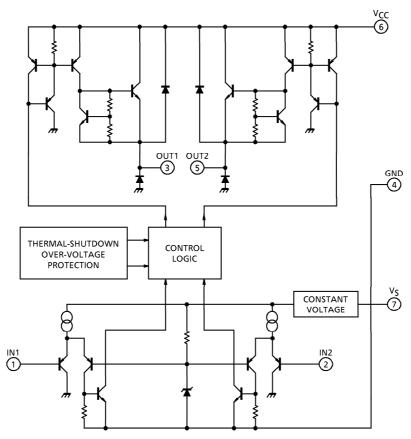
## **MAXIMUM RATINGS** (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Power Supply Voltage	Vcc	50 (1s)	V
Input Voltage	V <sub>IN</sub>	-0.3~V <sub>CC</sub> + 0.3	٧
Output Current	lout	300	mΑ
Power Dissipation	PD	0.92	W
Operating Temperature	T <sub>opr</sub>	- 40~110	°C
Storage Temperature	T <sub>stg</sub>	<b>-</b> 55∼150	°C
Lead Temperature·Time	T <sub>sol</sub>	260 (10s)	°C

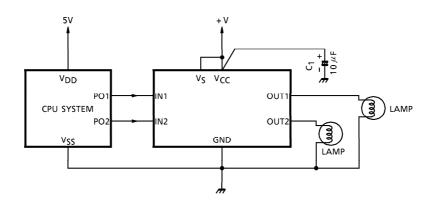
## ELECTRICAL CHARACTERISTICS (V<sub>S</sub>, $V_{CC} = 8 \sim 16V$ , $Ta = -40 \sim 110$ °C)

CHARACTERISTIC	SYMBOL	PIN	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
Power Supply Current	I <sub>S1</sub>			(IN1, IN2) = (L, L)		2.5	6		
(I)	I <sub>S2</sub>	Vs	l	(IN1, IN2) = (L, H) or (H, L)		4	9.5	mA	
(1)	I <sub>S3</sub>		1	(IN1, IN2) = (H, H)		4	9.5		
Power Supply Current	l <sub>CC1</sub>	Vcc	_	(IN1, IN2) = (L, L)	_	_	1	mA	
(II)	l <sub>CC2</sub>		-	(IN1, IN2) = (L, H)  or  (H, L)		7.5	15		
	I <sub>CC3</sub>		1	(IN1, IN2) = (H, H)		14	30		
Input Voltage	V <sub>IL</sub>	IN1/	I	_			0.8	V	
Input voltage	VIH	IN2	1	_	2.0	_	_		
Input Current	IJL	IN1/	1	V <sub>IN</sub> = 0.4V	- 20		_	μΑ	
input Current	ΠΗ	IN2	_	V <sub>IN</sub> = V <sub>CC</sub>		_	10		
Output Saturation Voltage	V <sub>sat</sub>	OUT1/ OUT2		I <sub>OUT</sub> = 300mA		1.0	1.5	V	
Output Leakage Current	ILEAK	OUT1/ OUT2		V <sub>out</sub> = 0V	- 100	_	_	μΑ	
Diode Forward Voltage	VF	OUT1/ OUT2		I <sub>F</sub> = 200mA	_	1.1	_	V	
Output Limit Current	I <sub>SC</sub>	OUT1/ OUT2		Ta = 25°C	0.3	0.55	_	А	
Chutdown Tomporoturo	T <sub>SD-H</sub>	OUT1/	_	OUT = ON→OFF	_	- 150	_	°C	
Shutdown Temperature	T <sub>SD-L</sub>	OUT2	_	OUT = OFF→ON	_	130	_	٠٠	
Over-Voltage Detection	V <sub>SD</sub>	Vcc	1	_	27	30	33	V	
Transfer Delay Time	t <sub>pLH</sub>			_		1	10	.,,c	
Transfer Delay Time	t <sub>pHL</sub>		_	_		1	10	$\mu$ s	

## **EQUIVALENT CIRCUIT**



#### **APPLICATION CIRCUIT**

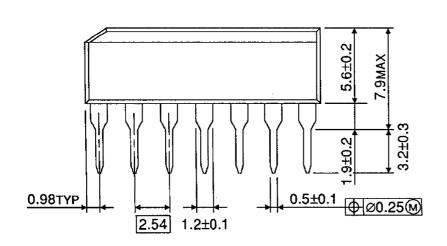


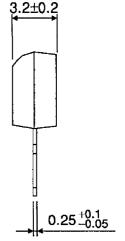
Cautions for wirings C<sub>1</sub> is for absorbing disturbance, noise, etc. Connect it as close to the IC as possible.

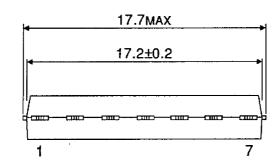
## OUTLINE DRAWING

SIP7-P-2.54A









Weight: 0.7g (Typ.)